

<p>FORM PTO/AIA 101 (Modified)</p> <p>INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p>				APPLICATION NO.: 10/588,833		ATTY. DOCKET NO.: H0498.70217US02	
				FILING DATE: August 9, 2006		CONFIRMATION NO.: 4453	
				APPLICANT: Lieber, et al.			
				GROUP ART UNIT: 2667		EXAMINER: Not yet assigned	
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